## NSN 5961-01-270-7605

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-270-7605 **Inclosure Material:** Metal **Overall Length:** Between 0.130 inches and 0.160 inches **Overall Diameter:** Between 0.145 inches and 0.180 inches **End Application:** 2350-01-248-7619 fighting vehicle, hs m2a1; 2350-01-248-7620 fighting vehicle, hs m3a1 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.00 amperes collector current, dc peak and 500.00 milliamperes all primaries preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No